

# **SCR**

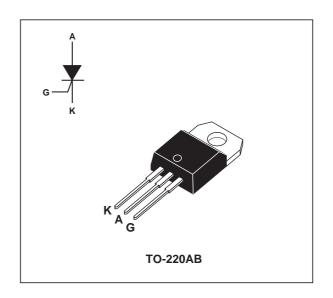
## **FEATURES**

- High surge capability
- High on-state current
- High stability and reliability

### **DESCRIPTION**

The TYN606 and TYN1006 Family of Silicon Controlled Rectifiers are high performance glass passivated technology.

This general purpose Family of Silicon Controlled Rectifiers is designed for power supply up to 400Hz on resistive or inductive load.



## **ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter	Value	Unit	
I <sub>T(RMS)</sub>	RMS on-state current (180° conduction angle)	$Tc = 110^{\circ}C$	6	Α
I <sub>T(AV)</sub>	Average on-state current (180° conduction angle, single phase circuit)	3.8	А	
I <sub>TSM</sub>	Non repetitive surge peak on-state current	tp = 8.3ms	73	Α
	(Tj initial = 25°C)		70	
I <sup>2</sup> t	I <sup>2</sup> t value	24.5	A <sup>2</sup> s	
dl/dt	dI/dt Critical rate of rise of on-state current Gate supply: I <sub>G</sub> = 100mA dI <sub>G</sub> /dt = 1A/µs			
Tstg Tj	Storage and operating junction temperature range			°C
TI	TI Maximum lead soldering temperature during 10s at 4.5mm from case			°C

Symbol	Dozomotov	TY	Unit	
	Parameter	606 1006		
V <sub>DRM</sub> V <sub>RRM</sub>	Repetitive peak off-state voltage Tj = 125°C	600	1000	V

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### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth (j-a)	Junction to ambient	60	°C/W
Rth (j-c) DC	Junction to case for DC	2.5	°C/W

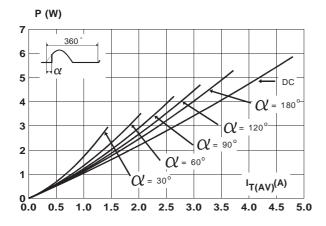
## **GATE CHARACTERISTICS** (maximum values)

 $P_{G(AV)} = 1W$   $P_{GM} = 10W$  (tp = 20 $\mu$ s)  $I_{FGM} = 4A$  (tp = 20 $\mu$ s)  $V_{RGM} = 5V$ 

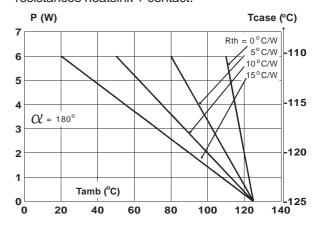
### **ELECTRICAL CHARACTERISTICS**

Symbol	Test conditions			Value	Unit
I <sub>GT</sub>	$V_D = 12V (DC)$ $R_L = 33\Omega$	Tj = 25°C	MAX.	15	mA
V <sub>GT</sub>	$V_D = 12V (DC)$ $R_L = 33\Omega$	Tj = 25°C	MAX.	1.5	V
V <sub>GD</sub>	$V_D = V_{DRM}$ $R_L = 3.3k\Omega$	Tj =110°C	MIN.	0.2	V
tgt	$V_D = V_{DRM}$ $I_G = 40 \text{mA}$ $dI_G/dt = 0.5 \text{A}/\mu\text{s}$	Tj = 25°C	TYP.	2	μs
IL	I <sub>G</sub> = 1.2I <sub>GT</sub>	Tj = 25°C	TYP.	50	mA
I <sub>H</sub>	I <sub>T</sub> = 100mA Gate open	Tj = 25°C	MAX.	30	mA
V <sub>TM</sub>	I <sub>TM</sub> = 12A tp = 380μs	Tj = 25°C	MAX.	1.6	V
I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>DRM</sub> rated V <sub>RRM</sub> rated	Tj = 25°C	MAX.	0.01	mA
		Tj = 110°C	MAX.	2	
dV/dt	Linear slope up to V <sub>D</sub> = 67% V <sub>DRM</sub> gate open	Tj = 110°C	MIN.	200	V/µs
tq	V <sub>D</sub> =67%V <sub>DRM</sub> I <sub>TM</sub> = 12A V <sub>R</sub> = 25V dI <sub>TM</sub> /dt=30 A/μs dV <sub>D</sub> /dt= 50V/μs	Tj = 110°C	TYP.	70	μs

**Fig. 1:** Maximum average power dissipation versus average on-state current.

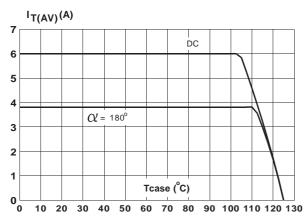


**Fig. 2:** Correlation between maximum average power dissipation and maximum allowable temperatures (Tamb and Tcase) for different thermal resistances heatsink + contact.



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**Fig. 3:** Average on-state current versus case temperature.



**Fig. 5:** Relative variation of gate trigger current versus junction temperature.

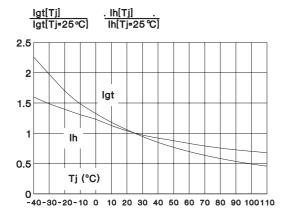
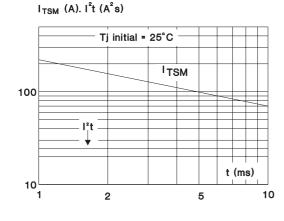
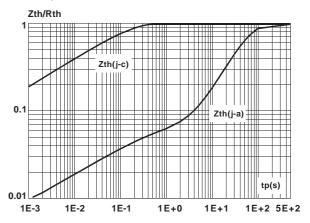


Fig. 7: Non repetitive surge peak on-state current for a sinusoidal pulse with width:  $t \le 10$ ms, and corresponding value of  $l^2t$ .



**Fig. 4:** Relative variation of thermal impedance versus pulse duration.



**Fig. 6:** Non repetitive surge peak on-state current versus number of cycles.

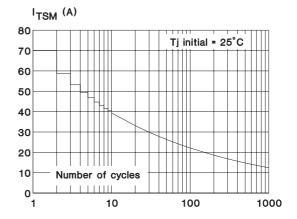
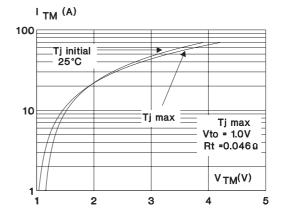


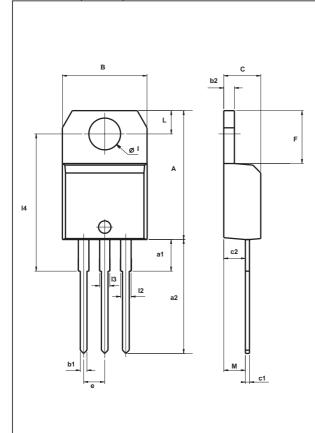
Fig. 8: On-state characteristics (maximum values).



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#### PACKAGE MECHANICAL DATA

TO-220AB (Plastic)



	DIMENSIONS					
REF.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
В	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
С	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
е	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
I	3.75		3.85	0.147		0.151
14	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
12	1.14		1.70	0.044		0.066
13	1.14		1.70	0.044		0.066
М		2.60			0.102	

## **OTHER INFORMATION**

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
TYNxx06	TYNxx06	TO-220AB	2.3 g	250	Bulk

- Epoxy meets UL94,V0
- Cooling method: C
- Recommended torque value: 0.8 m.N.
- Maximum torque value: 1 m.N.

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